TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHC153F, TC74VHC153FN, TC74VHC153FT

DUAL 4-CHANNEL MULTIPLEXER

The TC74VHC153 is an advanced high speed CMOS DUAL 4-CHANNEL MULTIPLEXERs fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Each of these data (1C0-1C3, 2C0-2C3) is selected by the two address inputs A and B.

Separate strobe inputs $(1\overline{G},\ 2\overline{G})$ are provided for each of the two four-line sections.

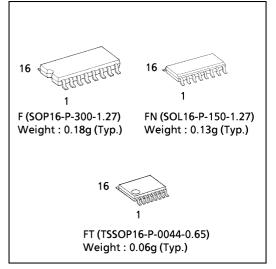
The strobe input (\overline{G}) can be used to inhibit the data output; the output is fixed in low level while the strobe input is held high.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

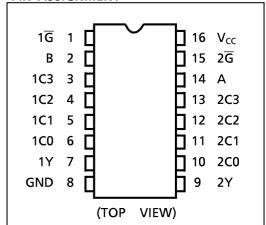
FEATURES:

- High Speed------t_{pd} = 5.0ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ·············· $I_{CC} = 4\mu A(Max.)$ at Ta = 25°C
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74ALS153

(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT

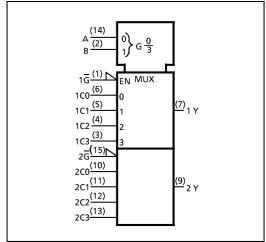


TRUTH TABLE

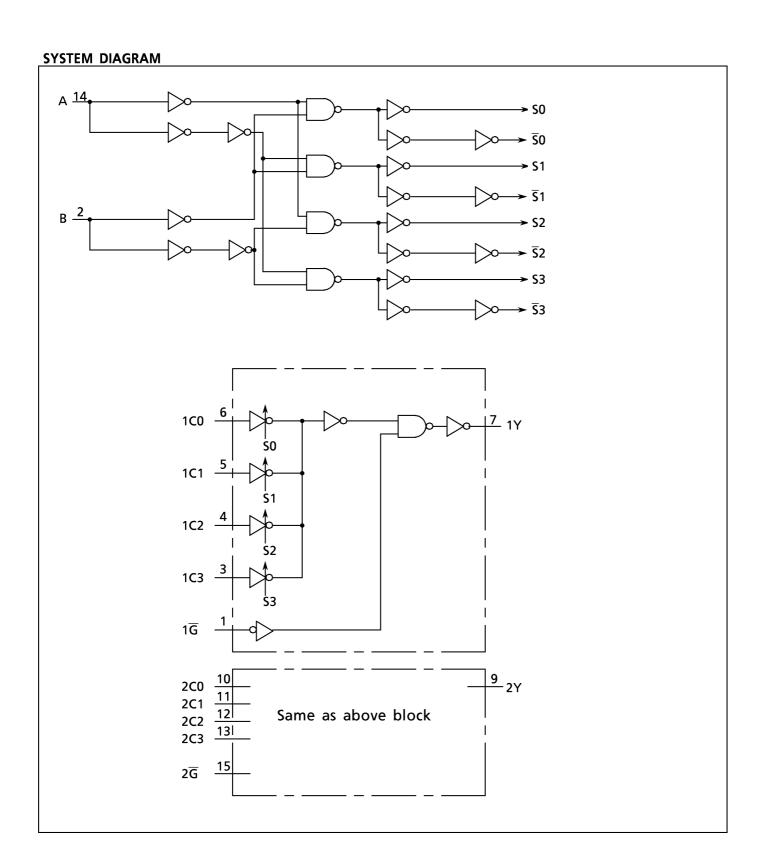
	SELECT INPUTS		DATA	INPUTS	STROBE	OUTPUTS	
В	Α	C 0	C 1	C 2	C 3	G	Y
Х	Χ	Х	Х	Х	Х	Н	L
L	L	L	Х	Х	Х	L	L
L	L	Н	Х	Х	Х	L	Н
L	Н	Х	L	Х	Х	L	L
L	Н	Х	Н	Х	Х	L	Н
Н	L	Х	Х	L	Х	L	L
Н	L	Х	Х	Н	Х	L	Н
Н	Н	Х	Х	Х	L	L	L
Н	Н	Х	Х	Х	Н	Ĺ	Н

X: Don't Care

IEC LOGIC SYMBOL



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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	VIN	-0.5~7.0	٧
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	٧
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} /Ground Current	I _{CC}	± 50	mΑ
Power Dissipation	P _D	180	mW
Storage Temperature	T _{stg}	−65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	2.0~5.5	٧
Input Voltage	VIN	0~5.5	٧
Output Voltage	V _{OUT}	0∼V _{cc}	V
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	dt/dv	$0 \sim 100 \text{ (Vcc} = 3.3 \pm 0.3 \text{V)}$ $0 \sim 20 \text{ (Vcc} = 5 \pm 0.5 \text{V)}$	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	CVMADOL	TEST CONDITION		V _{cc}	Ta = 25°C			Ta = - 4	UNIT	
PARAIVIETER	SYMBOL			(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level	.,		2.0 3.0~ 5.5	1.50	_	_	1.50	ı		
Input Voltage	V _{IH}				$V_{cc} \times 0.7$	_	_	$V_{cc} \times 0.7$	_	
Low - Level	.,			2.0	_	_	0.50	_	0.50	
Input Voltage	V _{IL}			3.0~ 5.5	_	_	$V_{cc} \times 0.3$	_	$V_{cc} \times 0.3$	V
	V _{OH}		L FO A	2.0 3.0	1.9 2.9	2.0 3.0	_	1.9 2.9		
High - Level Output Voltage		$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -50\mu A$	4.5	4.4	4.5	_	4.4	_	V
Calput (Citage			$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94	_	_	2.48 3.80		
			TOH = OTTIA	2.0	_	0.0	0.1	_	0.1	
Low - Level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 50 \mu A$	3.0	_	0.0	0.1	_	0.1	V
Output Voltage			1 4	4.5	_	0.0	0.1	_	0.1	•
		1111	$I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5	_	_	0.36 0.36	_	0.44 0.44	
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND		0~5.5	_	_	±0.1	_	± 1.0	Α.
Quiescent Supply Current I_{CC} $V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	_	40.0	μ A		

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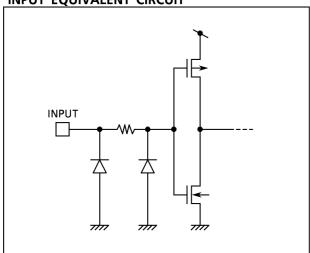
AC ELE	CTRICAL	CHARACTERISTICS	$(Input t_r = t)$	$t_f = 3 \text{ns}$	
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PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -4	UNIT		
FARAIVIETER	STIVIBOL		V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	OIVII
			3.3 ± 0.3	15	_	7.7	11.9	1.0	14.0	
Propagation Delay Time	t _{pLH}		3.3 ± 0.3	50	_	10.2	15.4	1.0	17.5	
(Cn-Y)	t _{pHL}		5.0 ± 0.5	15	_	5.0	7.7	1.0	9.0	
(,			3.0 ± 0.3	50	_	6.5	9.7	1.0	11.0	
	t _{pLH} t _{pHL}	H L	3.3 ± 0.3	15	_	10.8	16.7	1.0	19.5	
Propagation Delay Time				50	_	13.3	20.2	1.0	23.0	ns
(A,B-Y)			5.0 ± 0.5	15	_	6.8	9.9	1.0	11.5	
(* ',- ' ' '			3.0 ± 0.3	50	_	8.3	11.9	1.0	13.5	
			3.3 ± 0.3	15	_	6.3	10.1	1.0	12.0	
Propagation Delay Time	t _{pLH}			50	_	8.8	13.6	1.0	15.5	
(G-Y)	t _{pHL}		5.0 ± 0.5	15	_	4.4	6.4	1.0	7.5	
(- ',			3.0 ± 0.3	50	_	5.9	8.4	1.0	9.5	
Input Capacitance	C _{I N}				_	4	10	_	10	
Power Dissipation Capacitance	C _{PD}		(Note 1)		_	20	_	Ė	_	pF

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

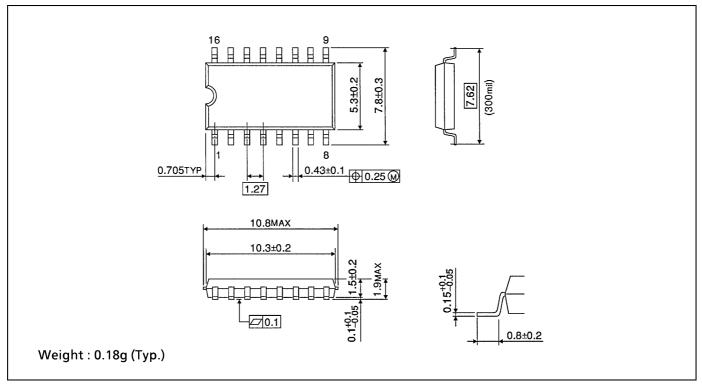




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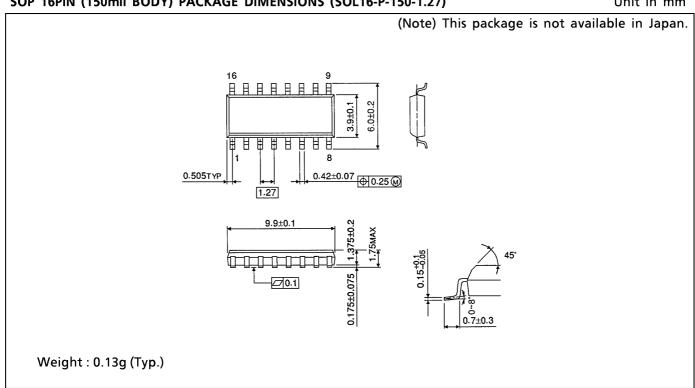
SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150-1.27)

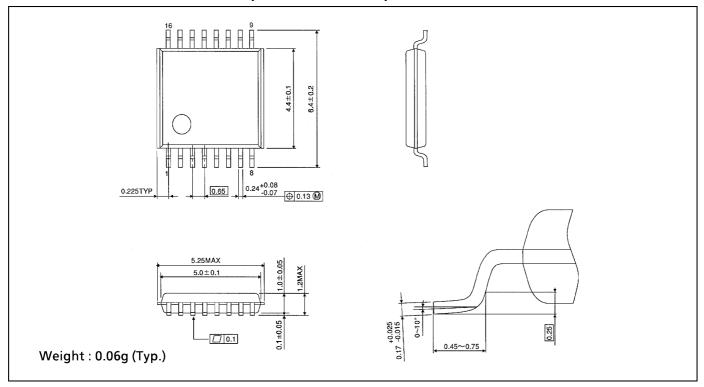
Unit in mm



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TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65)

Unit in mm



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